Triple Buffer

The NL37WZ16 is a high performance buffer with inputs operating from a 1.65 to 5.5 V supply.

The NL37WZ16 can be used as a line receiver which will receive slow input signals.

Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTL Compatible Interface Capability with 5 V TTL Logic with $V_{CC} = 3 \text{ V}$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Current Drive Capability is 24 mA at the Outputs
- Chip Complexity: FET = 94
- Pb-Free Package is Available

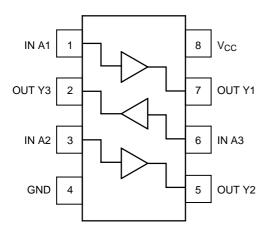


Figure 1. Pinout (Top View)

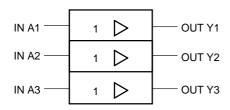
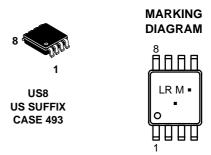


Figure 2. Logic Symbol



ON Semiconductor®

http://onsemi.com



LR = Device Code

M = Date Code*

■ Pb-Free Package

= PD-Free Package(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

PIN ASSIGNMENT

1	IN A1
2	OUT Y3
3	IN A2
4	GND
5	OUT Y2
6	IN A3
7	OUT Y1
8	V _{CC}

FUNCTION TABLE

A Input	▼ Output
L	L
н	Н

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	DC Supply Voltage		-0.5 to +7.0	V
VI	DC Input Voltage		$-0.5 \leq V_I \leq +7.0$	V
Vo	DC Output Voltage Outp	out in Z or LOW State (Note 1)	$-0.5 \le V_{O} \le 7.0$	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND	-50	mA
I _O	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current per Supply Pin		± 100	mA
I _{GND}	DC Ground Current per Ground Pin		± 100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature under Bias		+ 150	°C
θ_{JA}	Thermal Resistance	(Note 2)	333	°C/W
P_{D}	Power Dissipation in Still Air at 85°C		200	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage	Human Body Model (Note 3) Machine Model (Note 4) narged Device Model (Note 5)	> 2000 > 200 N/A	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Io absolute maximum rating must be observed.
- Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
 Tested to EIA/JESD22-A114-A.
- Tested to EIA/JESD22-A115-A.
 Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Symbol	Paramete	Min	Max	Unit	
V _{CC}	Supply Voltage	Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Input Voltage	(Note 6)	0	5.5	V
Vo	Output Voltage	(HIGH or LOW State)	0	5.5	V
T _A	Operating Free-Air Temperature		-40	+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	20 10 5	ns/V

^{6.} Unused inputs may not be left open. All inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

DC ELECTRICAL CHARACTERISTICS

			V _{CC}	T,	₄ = 25°C		-40°C ≤ 7	Γ _A ≤ 85°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
V _{IH}	High-Level Input Voltage		1.65 to 5.5	0.7 V _{CC}			0.7 V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65 to 5.5			0.3 V _{CC}		0.3 V _{CC}	V
V _{OH}	High-Level Output	$I_{OH} = -100 \mu A$	1.65 to 5.5	V _{CC} – 0.1	V _{CC}		V _{CC} – 0.1		V
	Voltage V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -4 \text{ mA}$	1.65	1.55	1.50		1.55		
	- IIV - III IL	$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.1		1.9		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2	2.4		2.2		1
		$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.7		2.4		
		I _{OH} = -24 mA	3.0	2.3	2.5		2.3		
		I _{OH} = -32 mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output	I _{OL} = 100 μA	1.65 to 5.5			0.1		0.1	V
	Voltage V _{IN} = V _{IH} or V _{IL}	I _{OL} = 4 mA	1.65			0.24		0.24	
		I _{OL} = 8 mA	2.3		0.20	0.3		0.3	
		I _{OL} = 12 mA	2.7		0.22	0.4		0.4	
		I _{OL} = 16 mA	3.0		0.28	0.4		0.4	
		I _{OL} = 24 mA	3.0		0.38	0.55		0.55	1
		I _{OL} = 32 mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	V _{IN} = V _{CC} or GND	0 to 5.5			± 0.1		±1.0	μΑ
l _{OFF}	Power Off-Output Leakage Current	V _{OUT} = 5.5 V	0			1		10	μΑ
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1		10	μΑ

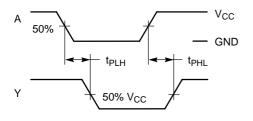
AC ELECTRICAL CHARACTERISTICS t_R = t_F = 2.5 ns; C_L = 50 pF; R_L = 500 Ω

				T _A = 25°C		$-40^{\circ}C \le T_A \le 85^{\circ}C$			
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit
t _{PLH}	Propagation Delay (Figure 3 and 4)	$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	1.8 ± 0.15	1.8	6.0	7.9	1.8	8.8	ns
t _{PHL}		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	2.5 ± 0.2	1.0	3.0	5.2	1.0	5.8	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	3.3 ± 0.3	0.8	2.3	3.6	0.8	4.0	
		$R_L = 500 \Omega, C_L = 50 pF$		1.2	3.0	4.6	1.2	5.1	
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	5.0 ± 0.5	0.5	18	2.9	0.5	3.2	
		$R_L = 500 \Omega, C_L = 50 pF$		0.8	2.4	3.8	0.8	4.2	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Parameter Condition		Unit
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_{I} = 0 V or V_{CC}	7.0	pF
C _{PD}	Power Dissipation Capacitance (Note 7)	10 MHz, $V_{CC} = 3.3 \text{ V}$, $V_I = 0 \text{ V or } V_{CC}$ 10 MHz, $V_{CC} = 5.5 \text{ V}$, $V_I = 0 \text{ V or } V_{CC}$	9 11	pF

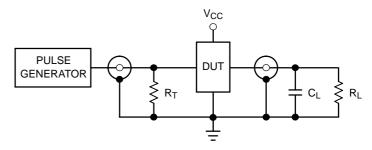
^{7.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption; P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.



PROPAGATION DELAYS

 $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

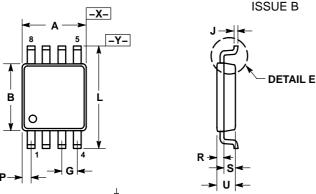
DEVICE ORDERING INFORMATION

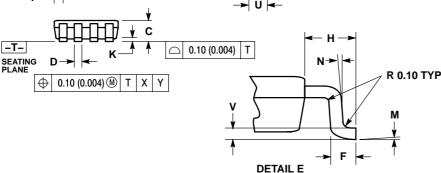
Device Order Number	Package Type	Tape and Reel Size [†]		
NL37WZ16US	US8	178 mm, 3000 Units / Tape & Reel		
NL37WZ16USG	US8 (Pb-Free)	178 mm, 3000 Units / Tape & Reel		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

US8 **US SUFFIX** CASE 493-02



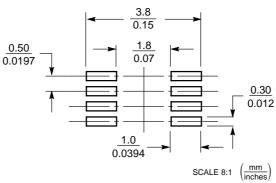


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION "A" DOES NOT INCLUDE MOLD FLASH, PROTRUSION OR GATE BURR.
 MOLD FLASH, PROTRUSION AND GATE BURR SHALL NOT EXCEED 0.140 MM
- 0.0055") PER SIDE.
 DIMENSION "B" DOES NOT INCLUDE
 INTER-LEAD FLASH OR PROTRUSION.
 INTER-LEAD FLASH AND PROTRUSION SHALL NOT E3XCEED 0.140 (0.0055") PER SIDE
- LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 0.0076-0.0203 MM. (300–800 °).
 ALL TOLERANCE UNLESS OTHERWISE
- SPECIFIED ±0.0508 (0.0002 ").

	MILLIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	1.90	2.10	0.075	0.083	
В	2.20	2.40	0.087	0.094	
С	0.60	0.90	0.024	0.035	
D	0.17	0.25	0.007	0.010	
F	0.20	0.35	0.008	0.014	
G	0.50	BSC	0.020	BSC	
Н	0.40	REF	0.016	REF	
J	0.10	0.18	0.004	0.007	
K	0.00	0.10	0.000	0.004	
L	3.00	3.20	0.118	0.126	
M	0 °	6 °	0 °	6 °	
N	5 °	10 °	5 °	10 °	
Р	0.23	0.34	0.010	0.013	
R	0.23	0.33	0.009	0.013	
S	0.37	0.47	0.015	0.019	
U	0.60	0.80	0.024	0.031	
V	0.12	BSC	0.005 BSC		

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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